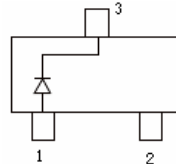


SOT-323 Plastic-Encapsulate Diodes

MMBD4448W SWITCHING DIODES

FEATURES

- Fast switching speed
- Surface mount package ideally suited for automatic insertion
- For general purpose switching applications
- High conductance
- Weight:0.006g
- RoHS product for packing code suffix "G"
- Halogen free product for packing code suffix "H"



SOT-323



1. ANODE
2. N, C
3. CATHODE

MARKING: KA3

Maximum Ratings @T_A=25°C

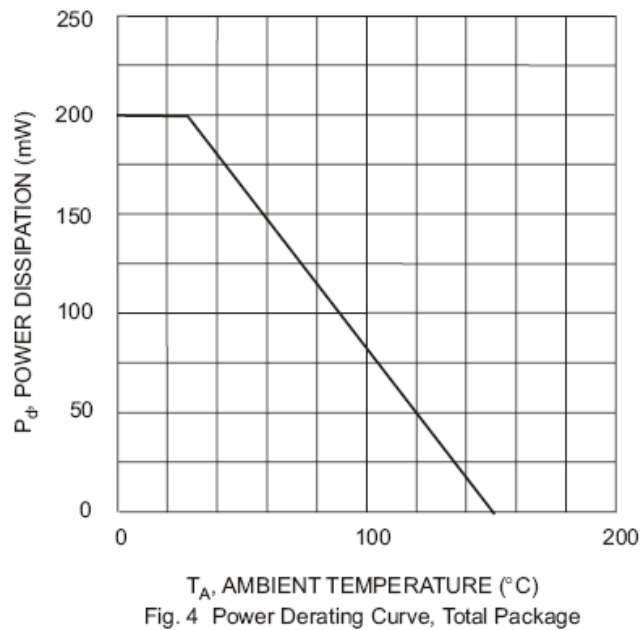
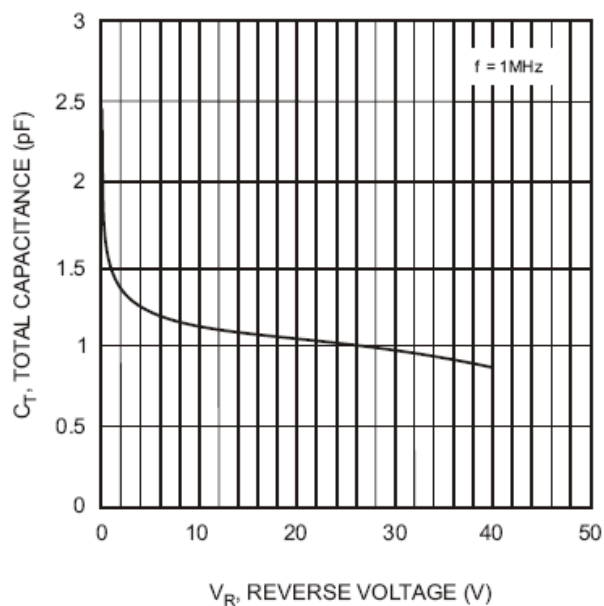
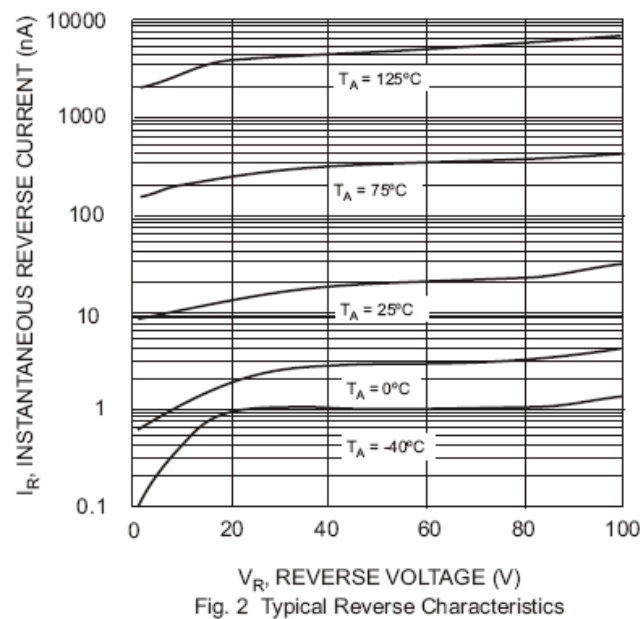
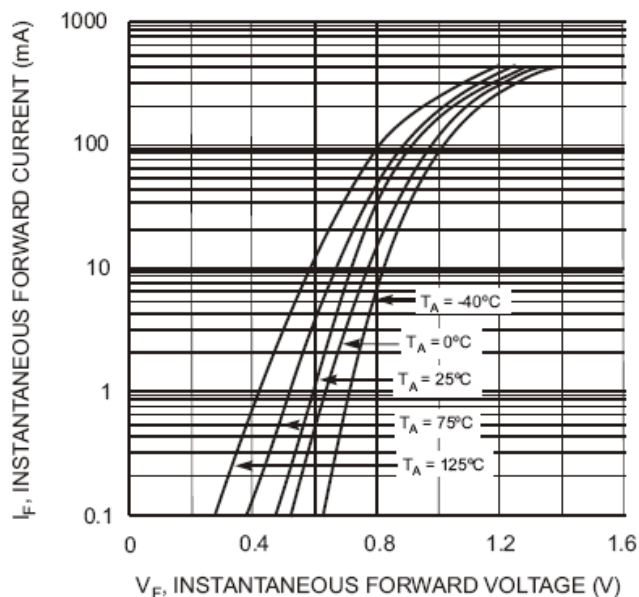
Parameter	Symbol	Limits	Unit
Non-Repetitive Peak reverse voltage	V _{RM}	100	V
Peak Repetitive Peak reverse voltage	V _{RRM}	75	V
Working Peak Reverse Voltage	V _{RWM}		
DC Blocking Voltage	V _R		
RMS Reverse Voltage	V _{R(RMS)}	53	V
Forward Continuous Current	I _{FM}	500	mA
Average Rectified Output Current	I _O	250	mA
Peak forward surge current @=1.0μs	I _{FSM}	4.0	A
@=1.0s		2.0	
Power Dissipation	P _d	200	mW
Thermal Resistance Junction to Ambient	R _{θJA}	625	°C/W
Storage temperature	T _{STG}	-65 to +150	°C

Electrical Ratings @T_A=25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V _{F1}	0.62		0.72	V	I _F =5mA
	V _{F2}			0.855	V	I _F =10mA
	V _{F3}			1.0	V	I _F =100mA
	V _{F4}			1.25	V	I _F =150mA
Reverse current	I _{R1}			2.5	μA	V _R =75V
	I _{R2}			25	nA	V _R =20V
Capacitance between terminals	C _T			4	pF	V _R =0V, f=1MHz
Reverse Recovery Time	t _{rr}			4	ns	I _F =I _R =10mA I _{rr} =0.1X I _R , R _L =100Ω

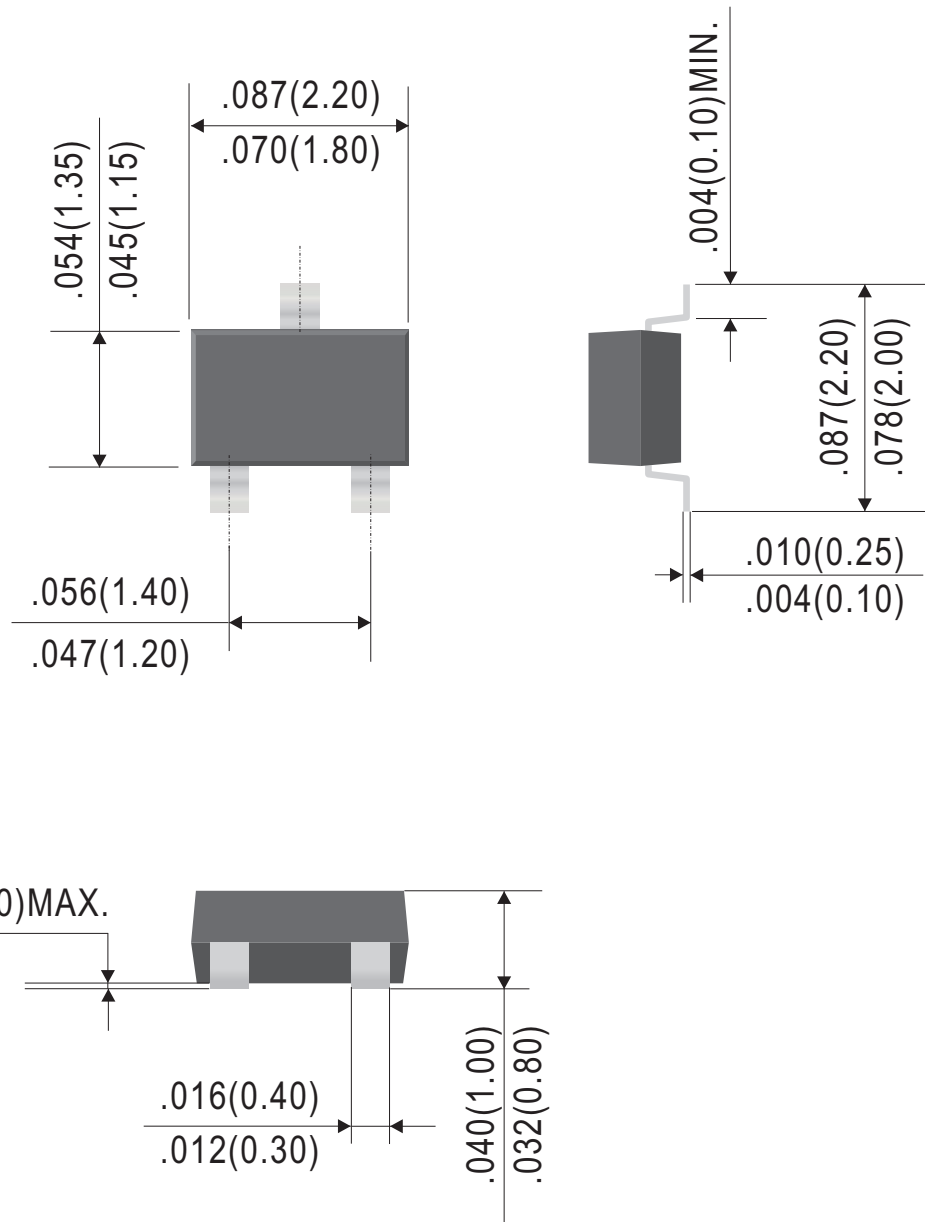
Typical Characteristics

MMBD4448W



Outline Drawing

SOT-323



Dimensions in inches and (millimeters)